



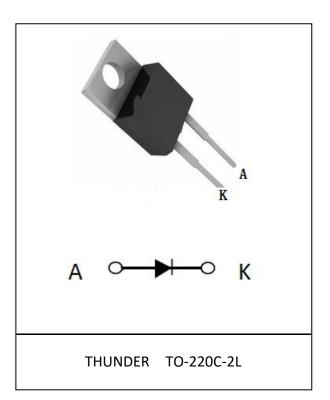
### Thunder High Power Products

# FRED Ultrafast Soft Recovery Diode, 8A

### Features:

- Ultrafast Recovery
- 175°C operating junction temperature
- High frequency operation
- Low power loss, less RFI and EMI
- Low I<sub>R</sub> value
- High surge capacity
- Epitaxial chip construction

Product Summary		
VR	1200 V	
lf(AV)	8A	
trr	40 ns	



## **Description/Applications**

These diodes are optimized to less losses and EMI/RFI in high frequency power conditioning system. The soft recovery behavior of the diodes offers the need as snubber in most applications. These devices are ideally suited for HF welding power converters and other applications where the switching losses are not significant portion of the total losses.

## **Absolute Maximum Ratings**

Parameter	Symbol	Test Conditions	Values	Units
Repetitive peak reverse voltage	Vrrm		1200	V
Continuous forward current	lf(AV)	Tc =110°C	8	
Single pulse forward current	IFSM	Tc =25°C	80	A
Maximum repetitive forward current	IFRM	Square wave, 20kHZ	16	
Operating junction	Tj		175	°C
Storage temperatures	Tstg		-55 to +175	°C





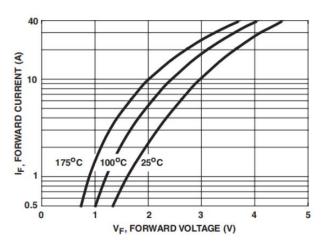
# Electrical characteristics (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур.	Max.	Units
Breakdown voltage	Vbr,		1200			
Blocking voltage	VR	Ir=100µA	1200			
Forward voltage (Per Diode)		IF=8A		2.10	2.50	V
	VF	IF=8A, Tj =125°C		1.95	2.50	
Reverse leakage current(Per Diode)		Vr= Vrrm			20	
	Tj=150°C, Vr=1200V			200	μΑ	
Reverse recovery time(Per Diode)	+	I <sub>F</sub> =0.5A, I <sub>R</sub> =1A, I <sub>RR</sub> =0.25A		40	50	20
	Lrr	I <sub>F</sub> =1A,V <sub>R</sub> =30V, di/ <i>dt</i> =200A/us		25	35	ns

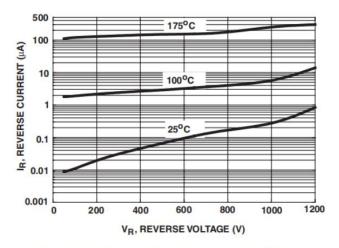
# **Thermal characteristics**

Paramter	Symbol	Тур	Units
R <sub>θJC</sub>	Junction-to-Case	3.0	°C/W

## **Electrical performance (typical)**













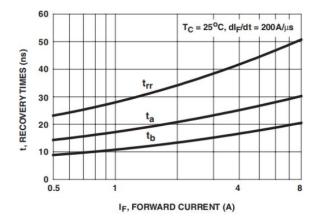


FIGURE 3. trr, ta AND tb CURVES vs FORWARD CURRENT

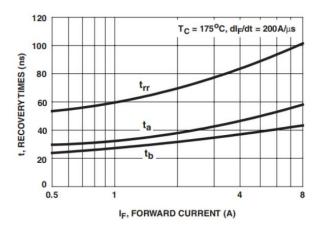


FIGURE 5. trr, ta AND tb CURVES vs FORWARD CURRENT

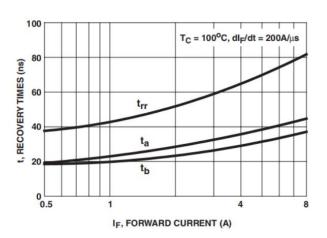


FIGURE 4. trn ta AND tb CURVES vs FORWARD CURRENT

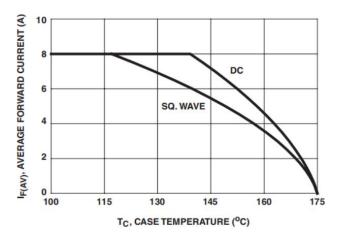


FIGURE 6. CURRENT DERATING CURVE

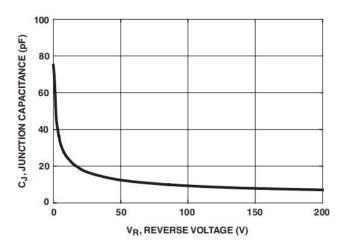
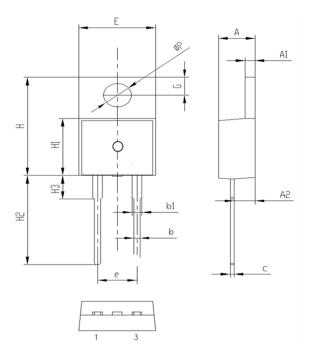


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE





## **Package Information**



#### TO-220C-2L PACKAGE

Symbol	Dimensions(millimeters)		
	Min.	Max.	
А	4.30	4.70	
A1	1.17	1.37	
A2	2.20	2.60	
b	0.60	1.00	
b1	1.17	1.37	
С	0.40	0.60	
е	4.88	5.28	
E	9.80	10.2	
Н	15.5	15.9	
H1	9.00	9.40	
H2	12.6	13.6	
H3	2.80	3.20	
G	2.60	3.00	
ΦP	3.40	3.80	

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